

B-TECH
(SEM III) THEORY EXAMINATION 2022-23
ELECTRONICS ENGINEERING

Time: 3 Hours

Total Marks: 100

Note: Attempt all Sections. If require any missing data; then choose suitably.

SECTION A

1. Attempt *all* questions in brief.

2 x 10 = 20

- (a) What is doping? Why it is needed
- (b) What is diode capacitance
- (c) What is dark current in tunnel diode
- (d) Can Zener diode operate in forward biased? If no why
- (e) For an N-channel JFET, if $I_{DSS} = 9 \text{ mA}$ and $V_P = 6 \text{ V}$, calculate I_D at $V_{GS} = 4 \text{ V}$
- (f) How op-amp can work as voltage follower circuit
- (g) In which mode can BJT work as a switch
- (h) What is CMRR in op-amp? What does it determine
- (i) What is advantage of Digital meter over analog meter
- (j)

SECTION B

2. Attempt any *three* of the following:

10x3=30

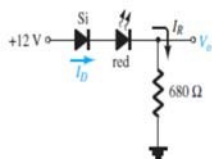
- (a) Draw V-I characteristic of conventional P-N diode and show the effect of temperature on this curve
- (b) With a neat circuit diagram and waveforms, explain the working of center-tapped full-wave rectifier. Show that efficiency of full-wave rectifier is 81%.
- (c) Draw CE transistor characteristic curve? Why CE is most popular configuration technique list its comparison
- (d) Derive output voltages for Integrator, Differentiator and Subtractor along with the circuit diagram using op-amp.
- (e) Explain construction and working of DMM with proper block diagram

SECTION C

3. Attempt any *one* part of the following:

10x1=10

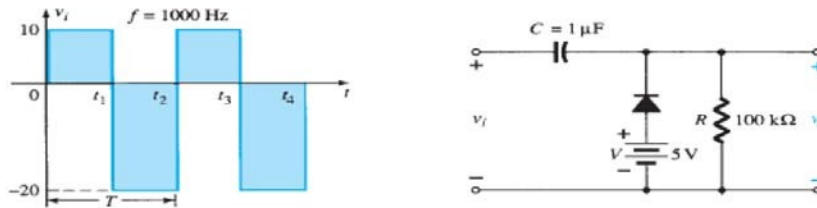
- (a) For the circuit shown calculate the output voltage, for red led the voltage drop is 1.8V



- (b) Explain Voltage Doubler Circuit and their types with a neat sketch? What is Diode current equation?

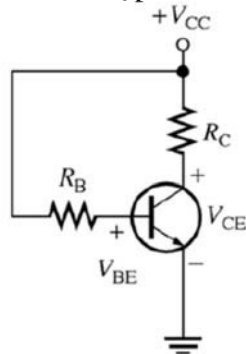
4. Attempt any *one* part of the following: 10x1=10

- (a) Explain what is tunnel diode and varactor diode along with their V-I characteristics curve. List application of both
 (b) For the circuit shown determine the output voltage



5. Attempt any *one* part of the following: 10x1=10

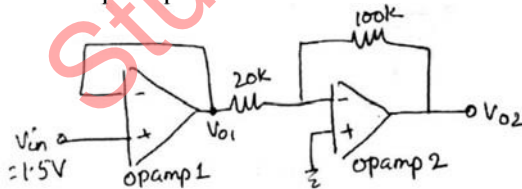
- (a) Determine Q point value if $\beta=200, V_{ce}=8V, R_B=320K, R_C=4K$



- (b) Explain construction and working of N channel depletion MOSFET? Draw the drain characteristic curve

6. Attempt any *one* part of the following: 10x1=10

- (a) Design an adder circuit using op-amp to obtain an output voltage of $V_o = -[0.1V_1 + 0.5V_2 + 2V_3]$, where V_1, V_2 and V_3 are input voltages. Draw the circuit diagram.
 (b) For the op-amp shown determine V_{o1} and V_{o2} . Also write the function of each op-amp



7. Attempt any *one* part of the following: 10x1=10

- (a) Explain in brief along with block diagram of Ramp type digital voltmeter using waveform?
 (b) Explain CRO with a neat sketch? How it can be used to measure frequency and phase determine?